	Tr. moo	Hits	Search Text	DBs
m	Туре	nics		
1	IS&R	4460	(("372/45") or ("372/49") or ("372/99")).CCLS.	USPAT; EPO; JPO; DERWENT; IBM TDB
2	BRS	1411	(dielectric adj3 thin amorphous adj2 Si SiN SiO2 Al2O3 "SiO.sub.2" "Al.sub.2" adj "O.sub.3") adj2 (film layer) and reflectivity	USPAT; EPO; JPO; DERWENT; IBM TDB
3	BRS	66	((("372/45") or ("372/49") or ("372/99")).CCLS.) and stoichiomet\$	USPAT; EPO; JPO; DERWENT; IBM TDB
4	BRS	138	((("372/45") or ("372/49") or ("372/99")).CCLS.) and protection	USPAT; EPO; JPO; DERWENT; IBM TDB
5	IS&R	2	("6067310").PN.	USPAT; EPO; JPO; DERWENT; IBM TDB
6	BRS	27	("4282494" "4309668" "4546481" "4942585" "4964135" "5045500" "5144634" "5491711" "5657336").PN.	USPAT; EPO; JPO; DERWENT; IBM TDB
7	BRS	0	6067310.URPN.	USPAT; EPO; JPO; DERWENT; IBM TDB
8	BRS	6	("5321713" "5799028").PN.	USPAT; EPO; JPO; DERWENT; IBM TDB
9	BRS	1393	((dielectric adj3 thin amorphous adj2 Si SiN SiO2 Al2O3 "SiO.sub.2" "Al.sub.2" adj "O.sub.3") adj2 (film layer) and reflectivity) not ((((("372/45") or ("372/49") or ("372/99")).CCLS.) and stoichiomet\$) (((("372/45") or ("372/49") or ("372/99")).CCLS.) and protection))	USPAT; EPO; JPO; DERWENT; IBM TDB
10	BRS	5	(((("372/45") or ("372/49") or ("372/99")).CCLS.) and stoichiomet\$) and ((dielectric adj3 thin amorphous adj2 Si SiN SiO2 Al2O3 "SiO.sub.2" "Al.sub.2" adj "O.sub.3") adj2 (film layer) and reflectivity)	USPAT; EPO; JPO; DERWENT; IBM TDB
11	BRS	52	passivation adj layer and ((dielectric adj3 thin amorphous adj2 Si SiN SiO2 Al2O3 "SiO.sub.2" "Al.sub.2" adj "O.sub.3") adj2 (film layer) and reflectivity)	USPAT; EPO; JPO; DERWENT; IBM TDB
12	BRS	19	4337443.URPN.	USPAT; EPO; JPO; DERWENT; IBM TDB

	Туре	Hits	Search Text	DBs
13	BRS	21	("3849738" "3914465" "3943462" "4095011" "4178564" "4254426").PN.	USPAT; EPO; JPO; DERWENT; IBM TDB
14	IS&R	3096	("372/45").CCLS.	USPAT; EPO; JPO; DERWENT; IBM TDB
15	IS&R	578	("372/49").CCLS.	USPAT; EPO; JPO; DERWENT; IBM TDB
16	BRS	4330	(dielectric adj3 thin amorphous adj2 Si SiN SiO2 Al2O3 "SiO.sub.2" "Al.sub.2" adj "O.sub.3") adj2 (film layer) and resistivity	USPAT; EPO; JPO; DERWENT; IBM TDB
17	BRS	5	(((("372/45") or ("372/49") or ("372/99")).CCLS.) and stoichiomet\$) and ((dielectric adj3 thin amorphous adj2 Si SiN SiO2 Al2O3 "SiO.sub.2" "Al.sub.2" adj "O.sub.3") adj2 (film layer) and resistivity)	USPAT; EPO; JPO; DERWENT; IBM TDB